

SAMTM Data Sheet SAM-1064-1.5-1ps-x, λ = 1064 nm

Laser wavelength $\lambda = 1064 \text{ nm}$

High reflection band $\lambda = 1020 ... 1100 \text{ nm}$

Absorptance $A_0 = 1.5 \%$ Modulation depth $\Delta R = 0.8 \%$ Non-saturable loss $A_{ns} = 0.7 \%$ Saturation fluence $\Phi_{sat} = 90 \ \mu \text{J/cm}^2$

Relaxation time constant $\tau \sim 1 \text{ ps}$

Damage threshold $\Phi = 3 \text{ mJ/cm}^2$

Chip area 4.0 mm x 4.0 mm; other dimensions on request

Chip thickness 450 µm

Protection the SAM is protected with a dielectric front layer

Mounting option \mathbf{x} denotes the type of mounting as follows:

x = 0unmounted $x = 12.7 \, \mathrm{g}$ glued on a gold plated Cu-cylinder with 12.7 mm \varnothing $x = 25.4 \, \mathrm{g}$ glued on a gold plated Cu-cylinder with 25.4 mm \varnothing $x = 12.7 \, \mathrm{s}$ soldered on a gold plated Cu-cylinder with 12.7 mm \varnothing $x = 25.4 \, \mathrm{s}$ soldered on a gold plated Cu-cylinder with 25.4 mm \varnothing $x = 25.0 \, \mathrm{w}$ soldered on a water cooled Cu-cylinder with 25.0 mm \varnothing x = FCmounted on a 1 m monomode fiber cable with FC connector

Low intensity spectral reflectance and dispersion coefficient D₂

